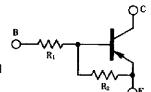


# COMPOUND TRANSISTOR AN1L3M

# on-chip resistor PNP silicon epitaxial transistor For mid-speed switching

#### **FEATURES**

• On-chip bias resistor  $(R_1=4.7 \; k\Omega, \; R_2=4.7 \; k\Omega)$ 



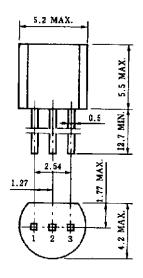
· Complementary transistor with AA1L3M

#### ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vcво	-60	V
Collector to emitter voltage	VCEO	<b>–50</b>	V
Emitter to base voltage	VEBO	-10	V
Collector current (DC)	Ic(DC)	-100	mA
Collector current (Pulse)	Ic(pulse) *	-200	mA
Total power dissipation	Рт	250	mW
Junction temperature	Tj	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

<sup>\*</sup> PW  $\leq$  10 ms, duty cycle  $\leq$  50 %

#### PACKAGE DRAWING (UNIT: mm)



Electrode Connection

1. Emitter EIAJ : SC-43B
2. Collector JEDEC: TO-92
3. Base IEC : PA33

## **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

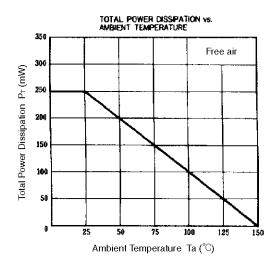
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = -50 \text{ V}, I_E = 0$			100	nA
DC current gain	h <sub>FE1</sub> **	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -5.0 \text{ mA}$	20	40	80	-
DC current gain	h <sub>FE2</sub> **	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -50 \text{ mA}$	70	110		-
Collector saturation voltage	VCE(sat) **	$I_C = -5.0 \text{ mA}, I_B = -0.25 \text{ mA}$		-0.02	-0.3	V
Low level input voltage	VIL **	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -100 \ \mu\text{A}$		-1.1	-0.8	V
High level input voltage	V <sub>IH</sub> **	$V_{CE} = -0.2 \text{ V}, \text{ Ic} = -5.0 \text{ mA}$	-3.0	-1.5		V
Input resistance	R <sub>1</sub>		3.29	4.7	6.11	kΩ
Resistance ratio	R <sub>1</sub> /R <sub>2</sub>		0.9	1.0	1.1	-
Turn-on time	ton	$Vcc = -5 \text{ V}, \text{ RL} = 1 \text{ k}\Omega$			0.5	μs
Storage time	tstg	$V_1 = -5 \text{ V}, \text{ PW} = 2 \mu \text{s}$			3.0	μs
Turn-off time	toff	duty cycle≤2 %			5.0	μs

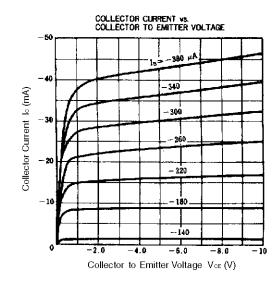
<sup>\*\*</sup> PW  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2 %

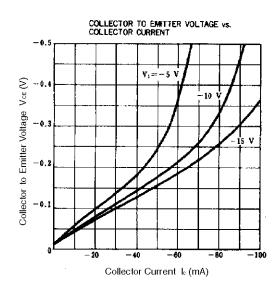
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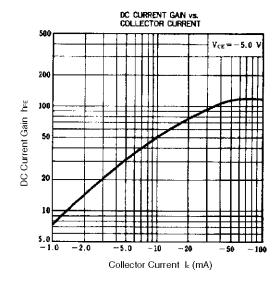


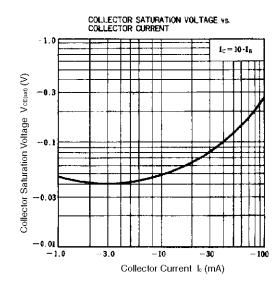
### TYPICAL CHARACTERISTICS (Ta = 25°C)

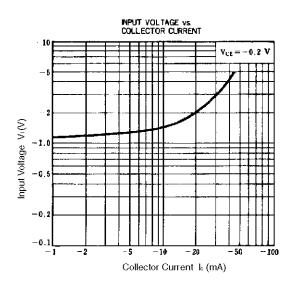


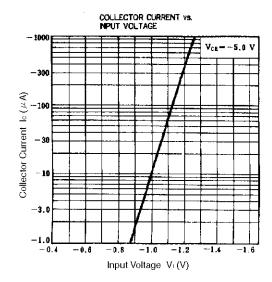


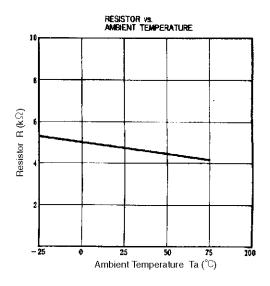












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